

## QUAD BUS BUFFERS (3-STATE)

- **HIGH SPEED**  
 $t_{PD} = 10 \text{ ns (TYP.)}$  at  $V_{CC} = 5V$
- **LOW POWER DISSIPATION**  
 $I_{CC} = 4 \mu\text{A (MAX.)}$  at  $T_A = 25^\circ\text{C}$
- **HIGH NOISE IMMUNITY**  
 $V_{NIH} = V_{NIL} = 28\% V_{CC}$  (MIN.)
- **OUTPUT DRIVE CAPABILITY**  
 15 LSTTL LOADS
- **SYMMETRICAL OUTPUT IMPEDANCE**  
 $|I_{OH}| = I_{OL} = 6 \text{ mA (MIN.)}$
- **BALANCED PROPAGATION DELAYS**  
 $t_{PLH} = t_{PHL}$
- **WIDE OPERATING VOLTAGE RANGE**  
 $V_{CC}$  (OPR) = 2V to 6V
- **PIN AND FUNCTION COMPATIBLE**  
 WITH 54/74LS125/126

### DESCRIPTION

The M54/74HC125 and the M54/74HC126 are high speed CMOS QUAD BUS BUFFERS (3-STATE) fabricated in silicon gate C<sup>2</sup>MOS technology.

They have the same high speed performance of LSTTL combined with true CMOS low power consumption.

These devices require the 3-STATE control input G to be taken high to make the output go into the high impedance state.

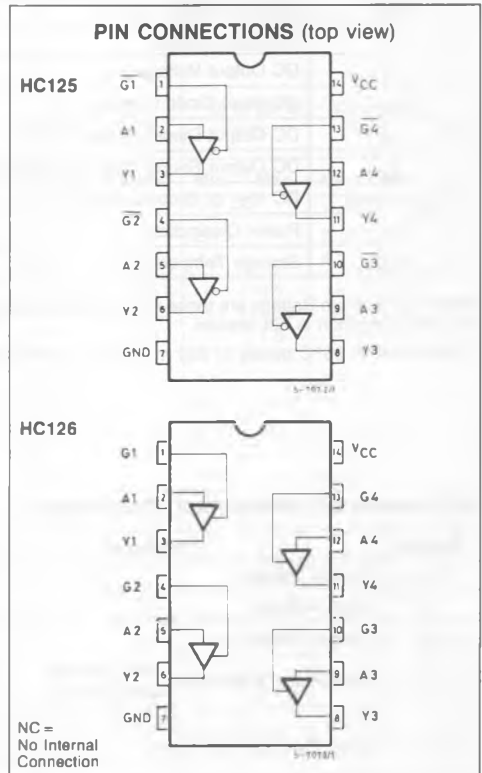
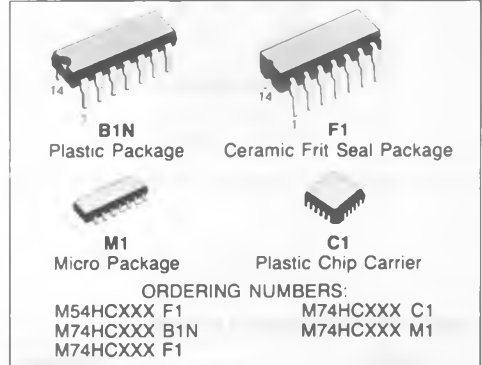
All inputs are equipped with protection circuits against static discharge and transient excess voltage.

### TRUTH TABLES

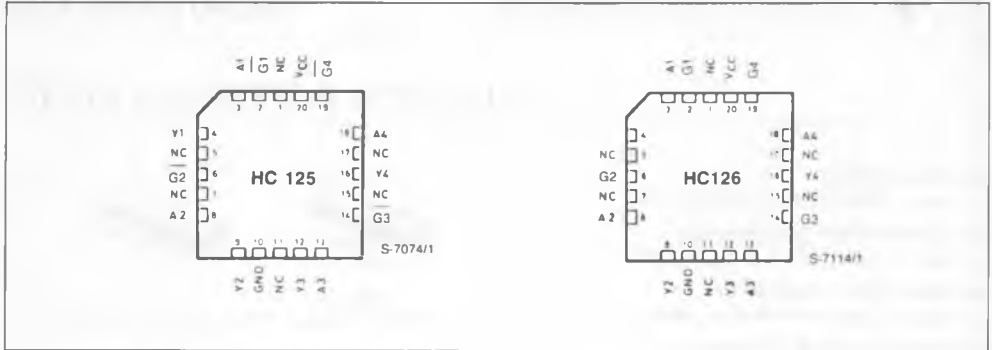
HC 125		
INPUTS	OUTPUT	
A	$\bar{G}$	Y
X	H	Z
L	L	L
H	L	H

HC126		
INPUTS	OUTPUT	
A	G	Y
X	L	Z
L	H	L
H	H	H

X: DON'T CARE    Z: HIGH IMPEDANCE



## CHIP CARRIER



## ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
$V_{CC}$	Supply Voltage	-0.5 to 7	V
$V_I$	DC Input Voltage	-0.5 to $V_{CC} + 0.5$	V
$V_O$	DC Output Voltage	-0.5 to $V_{CC} + 0.5$	V
$I_{IK}$	DC Input Diode Current	$\pm 20$	mA
$I_{OK}$	DC Output Diode Current	$\pm 20$	mA
$I_O$	DC Output Source Sink Current Per Output Pin	$\pm 35$	mA
$I_{CC}$ or $I_{GND}$	DC $V_{CC}$ or Ground Current	$\pm 70$	mA
$P_D$	Power Dissipation	500 (*)	mW
$T_{stg}$	Storage Temperature	-65 to 150	$^{\circ}C$

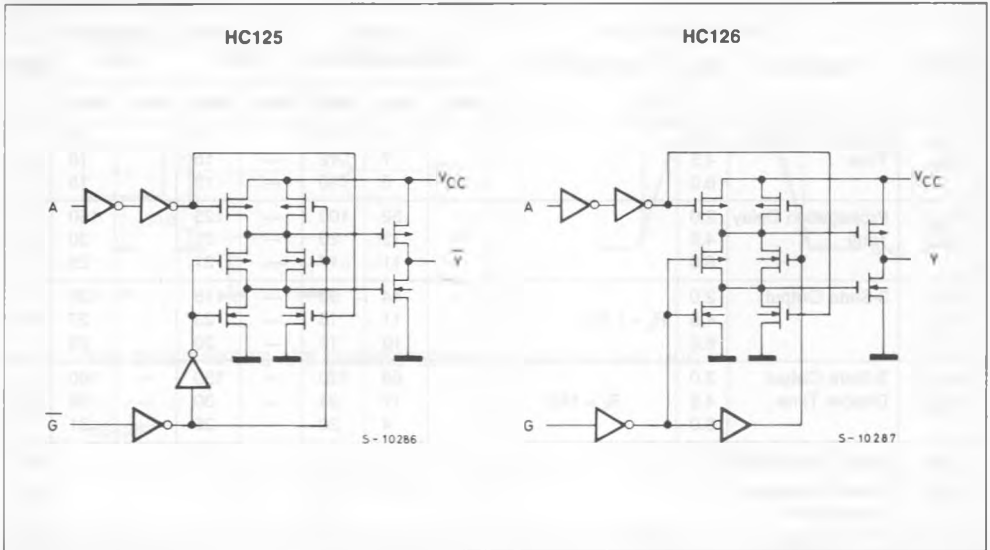
Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

(\*) 500 mW:  $\cong$  65 $^{\circ}C$  derate to 300 mW by 10 mW/ $^{\circ}C$ : 65 $^{\circ}C$  to 85 $^{\circ}C$ .

## RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
$V_{CC}$	Supply Voltage	2 to 6	V
$V_I$	Input Voltage	0 to $V_{CC}$	V
$V_O$	Output Voltage	0 to $V_{CC}$	V
$T_A$	Operating Temperature	74HC Series 54HC Series	$^{\circ}C$
$t_r, t_f$	Input Rise and Fall Time	$V_{CC}$ { 2 V 4.5V 6 V	ns
		0 to 1000 0 to 500 0 to 400	

## CIRCUIT DIAGRAM



## DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	V <sub>CC</sub>	Test Condition	T <sub>A</sub> = 25°C 54HC and 74HC			-40 to 85°C 74HC		-55 to 125°C 54HC		Unit	
				Min.	Typ.	Max.	Min.	Max.	Min.	Max.		
V <sub>IH</sub>	High Level Input Voltage	2.0 4.5 6.0		1.5 3.15 4.2	— — —	— — —	1.5 3.15 4.2	— — —	1.5 3.15 4.2	— — —	V	
V <sub>IL</sub>	Low Level Input Voltage	2.0 4.5 6.0		— — —	— — —	0.5 1.35 1.8	— — —	0.5 1.35 1.8	— — —	0.5 1.35 1.8	V	
V <sub>OH</sub>	High Level Output Voltage	2.0 4.5 6.0 4.5 6.0	V <sub>I</sub>	I <sub>O</sub> -20 μA -6.0 mA -7.8 mA	1.9	2.0	—	1.9	—	1.9	—	V
			V <sub>IH</sub> or V <sub>IL</sub>		4.4	4.5	—	4.4	—	4.4	—	
					5.9	6.0	—	5.9	—	5.9	—	
					4.18	4.31	—	4.13	—	4.10	—	
				5.68	5.8	—	5.63	—	5.60	—		
V <sub>OL</sub>	Low Level Output Voltage	2.0 4.5 6.0 4.5 6.0	V <sub>IH</sub> or V <sub>IL</sub>	20 μA 6.0 mA 7.8 mA	—	0.0	0.1	—	0.1	—	0.1	V
					—	0.0	0.1	—	0.1	—	0.1	
					—	0.0	0.1	—	0.1	—	0.1	
					—	0.17	0.26	—	0.33	—	0.40	
				—	0.18	0.26	—	0.33	—	0.40		
I <sub>I</sub>	Input Leakage Current	6.0	V <sub>I</sub> = V <sub>CC</sub> or GND	—	—	±0.1	—	±1.0	—	±1.0	μA	
I <sub>OZ</sub>	3-State Output Off-State Current	6.0	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>O</sub> = V <sub>CC</sub> or GND	—	—	±0.5	—	±5.0	—	±10	μA	
I <sub>CC</sub>	Quiescent Supply Current	6.0	V <sub>I</sub> = V <sub>CC</sub> or GND	—	—	4	—	40	—	80	μA	

AC ELECTRICAL CHARACTERISTICS ( $C_L = 50\text{pF}$ , Input  $t_r = t_f = 6\text{ns}$ )

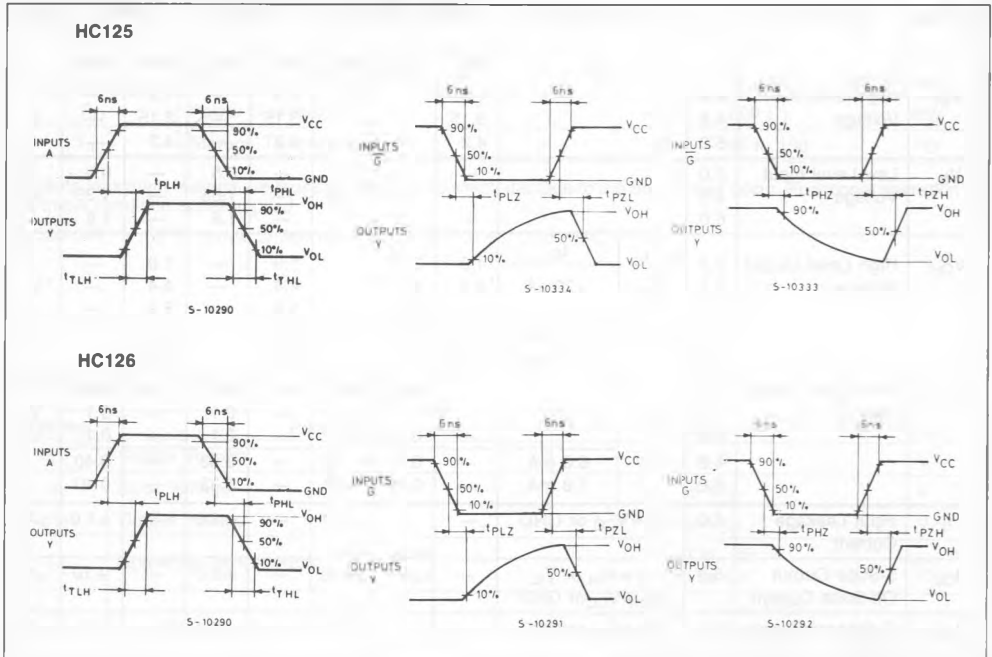
Symbol	Parameter	$V_{CC}$	Test Condition	$T_A = 25^\circ\text{C}$ 54HC and 74HC			$-40$ to $85^\circ\text{C}$ 74HC		$-55$ to $125^\circ\text{C}$ 54HC		Unit
				Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
$t_{TLH}$ $t_{THL}$	Output Transition Time	2.0 4.5 6.0		— — —	25 7 6	60 12 10	— — —	75 15 13	90 18 15	ns	
$t_{PLH}$ $t_{PHL}$	Propagation Delay Time	2.0 4.5 6.0		— — —	52 13 11	100 20 17	— — —	125 25 21	150 30 26	ns	
$t_{PLH}$ $t_{PHL}$	3-State Output	2.0 4.5 6.0	$R_L = 1\text{K}\Omega$	— — —	44 11 19	90 18 15	— — —	115 23 20	135 27 23	ns	
$t_{PLZ}$ $t_{PHZ}$	3-State Output Disable Time	2.0 4.5 6.0	$R_L = 1\text{K}\Omega$	— — —	68 17 4	120 24 20	— — —	150 30 26	180 36 31	pF	
$C_{IN}$	Input Capacitance			—	5	10	—	10		pF	
$C_{PD} (*)$	Power Dissipation Capacitance			—	34	—	—	—		pF	

Note (\*)  $C_{PD}$  is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the following equation.

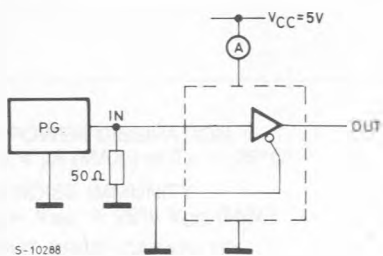
$$I_{CC(\text{opr})} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4 \text{ (per Circuit)}$$

## SWITCHING CHARACTERISTICS TEST WAVEFORM

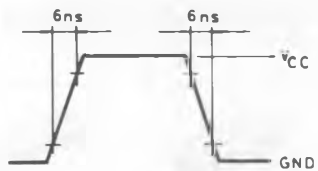


TEST CIRCUIT  $I_{CC}$  (Opr.)

## HC125

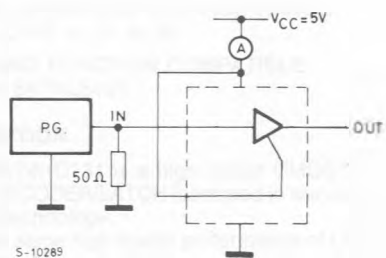


## INPUT WAVEFORM

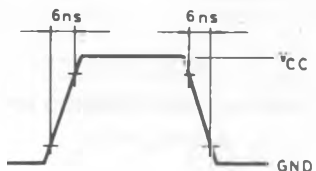


THE OTHER INPUTS ARE CONNECTED TO  $V_{CC}$  LINE OR GND LINE.

## HC126



## INPUT WAVEFORM



THE OTHER INPUTS ARE CONNECTED TO  $V_{CC}$  LINE OR GND LINE.